

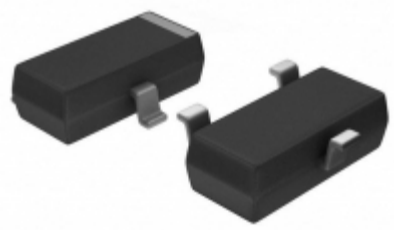

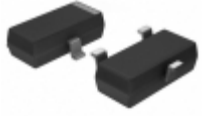


	<h2 style="color: red;">FJV4101RMTF</h2>
	<p>Hersteller-Teilenummer: FJV4101RMTF</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: TRANS PREBIAS PNP 200MW SOT23-3</p> <p>Datenblätter:  1.FJV4101RMTF.pdf  2.FJV4101RMTF.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 18000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FJV4101RMTF
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PREBIAS PNP 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	18000 pcs Stock
detaillierte Beschreibung	Pre-Biased Bipolar Transistor (BJT) PNP - Pre-Biased
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	PNP - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 500µA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	20 @ 10mA, 5V
Frequenz - Übergang	200MHz
Verpackung	Tape & Reel (TR)
Basisteilenummer	FJV4101
Widerstand - Basis (R1)	4.7 kOhms
Widerstand - Emitterbasis (R2)	4.7 kOhms
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FJV4101RMTF-ND





























FJV4101RMTF ist neu im Original, Suche FJV4101RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV4101RMTF AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV4101RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FJV4102RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV3114RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV4102RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV3115RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>
 <p>FJV4101RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4103RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4102RLIMTF FAI FJV4102RLIMTF FAI</p>	 <p>FJV3115RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>

heiße Teile

Mehr

 FJV3104RMTF	 FJV3104RMTF	 FJV3105RMTF	 FJV3105RMTF	 FJV3106RMTF
 FJV3106RMTF	 FJV3107RMTF	 FJV3107RMTF	 FJV3108RMTF	 FJV3108RMTF
 FJV3109R	 FJV3109RMTF	 FJV3109RMTF	 FJV3110RMTF	 FJV3110RMTF
 FJV3111RMTF	 FJV3111RMTF	 FJV3112RMTF	 FJV3112RMTF	 FJV3113RMTF
 FJV3113RMTF	 FJV3114RMTF	 FJV3114RMTF	 FJV3115RMTF	 FJV3115RMTF
 FJV4101RMTF	 FJV4102RLIMTF	 FJV4102RMTF	 FJV4102RMTF	 FJV4103RMTF
 FJV4103RMTF	 FJV4104RMTF	 FJV4104RMTF	 FJV4105RMTF	 FJV4105RMTF
 FJV4106RMTF	 FJV4106RMTF	 FJV4107RMTF	 FJV4107RMTF	 FJV4108RMTF
 FJV4108RMTF	 FJV4109RMTF	 FJV4109RMTF	 FJV4110RMTF	 FJV4110RMTF
 FJV4111RMTF	 FJV4111RMTF	 FJV4112RMTF	 FJV4112RMTF	 FJV4113RMTF

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